



2N3636UB Information

Heisener.com

Part Number 2N3636UB

Manufacturer Microsemi Corporation

Category Discrete Semiconductor Products

Transistors - Bipolar (BJT) - Single

Description TRANS PNP 175V 1A

Package 3-SMD, No Lead

For the pricing/inventory/lead time, please contact

us

For Reference Only

Website: https://www.heisener.com
E-mail: salesdept@heisener.com



Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.









2N3636UB Specifications

Manufacturer Part Number	2N3636UB
Manufacturer	Microsemi Corporation
Category	Discrete Semiconductor Products
	Transistors - Bipolar (BJT) - Single
Package	3-SMD, No Lead
Series	-
Transistor Type	PNP
Current - Collector (Ic) (Max)	1A
Voltage - Collector Emitter Breakdown (Max)	175V
Vce Saturation (Max) @ Ib, Ic	600mV @ 5mA, 50mA
Current - Collector Cutoff (Max)	10μΑ
DC Current Gain (hFE) (Min) @ Ic, Vce	50 @ 50mA, 10V
Power - Max	1.5W
Frequency - Transition	-
Operating Temperature	-65°C ~ 200°C (TJ)
Mounting Type	Surface Mount
Package / Case	3-SMD, No Lead
Supplier Device Package	3-SMD
	Report errors?

2N3636UB Guarantees



Quality Guarantees

We provide 90 days warranty. *

If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.



Service Guarantees

We guarantee 100% customer satisfaction.

Our experienced sales team and tech support team back our services to satisfy all our customers.

2N3636UB Payment Methods



















2N3636UB Shipping Methods













If you have any question about 2N3636UB, please do not hesitate to contact us!

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